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[Diodes Incorporated](#)

[FZT753TA](#)

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A Product Line of
 Diodes Incorporated



FZT753

100V PNP HIGH PERFORMANCE TRANSISTOR IN SOT223

Features

- $BV_{CEO} > -100V$
- $I_c = -2A$ High Continuous Current
- $I_{CM} = -6A$ Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)} < -300mV$ @ $-1A$
- Complementary NPN Type: FZT653
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

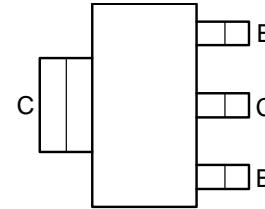
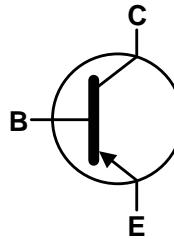
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.112 grams (Approximate)

SOT223



Top View



Ordering Information (Notes 4 & 5)

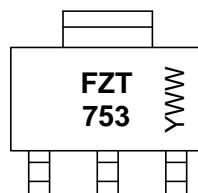
Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT753TA	AEC-Q101	FZT753	7	12	1,000
FZT753QTA	Automotive	FZT753	7	12	1,000
FZT753TC	AEC-Q101	FZT753	13	12	4,000
FZT753QTC	Automotive	FZT753	13	12	4,000

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT223



FZT 753 = Product Type Marking Code
 YWW = Date Code Marking
 Y or Y = Last Digit of Year (ex: 5= 2015)
 WW or WW = Week Code (01~53)

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-120	V
Collector-Emitter Voltage	V_{CEO}	-100	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-2	A
Peak Pulse Current	I_{CM}	-6	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	3.0	W
		2.0	
		1.6	
		1.2	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	41.7	°C/W
		62.5	
		78.1	
		104	
Thermal Resistance Junction to Lead	$R_{\theta JL}$	12.9	
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

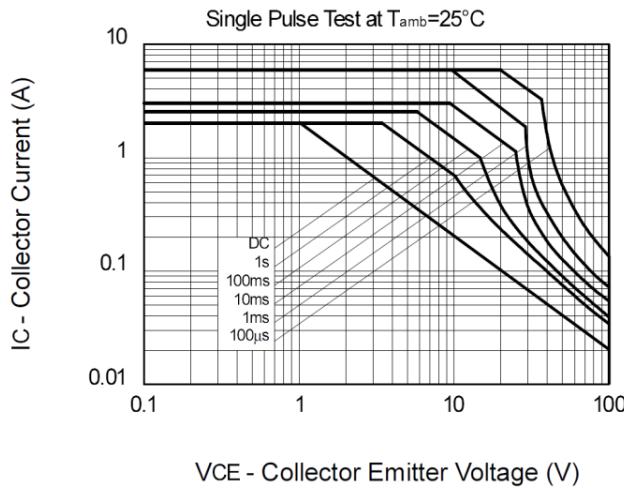
ESD Ratings (Note 11)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

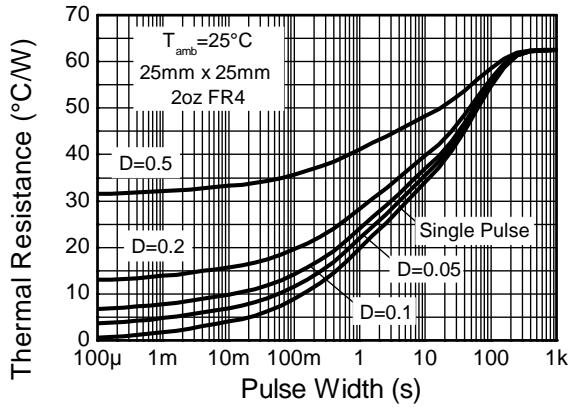
Notes:

6. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.
8. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.
9. Same as Note 6, except the device is mounted on minimum recommended pad layout.
10. Thermal resistance from junction to solder-point (at the end of the collector lead).
11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

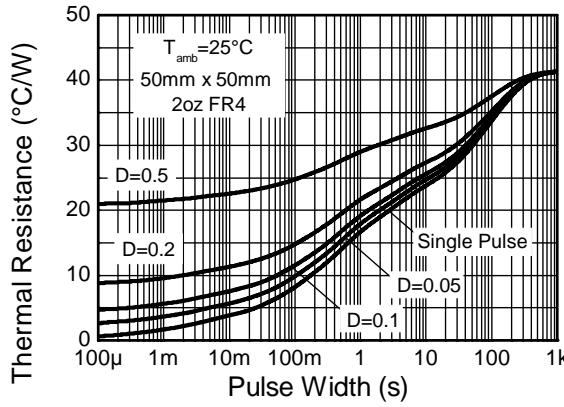
Thermal Characteristics and Derating Information



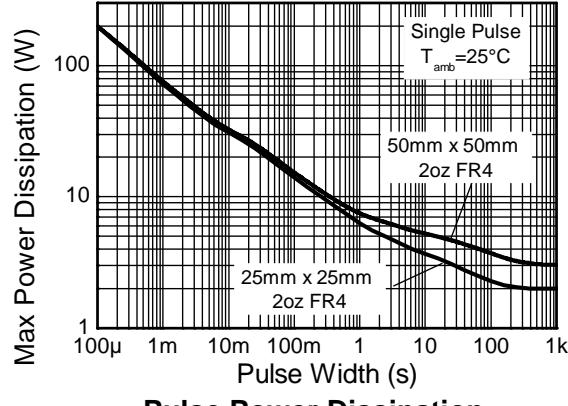
Safe Operating Area



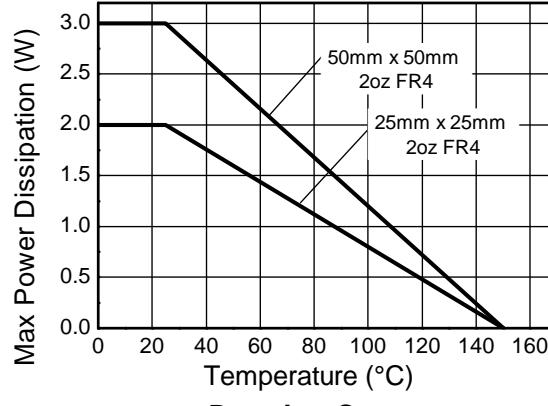
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve



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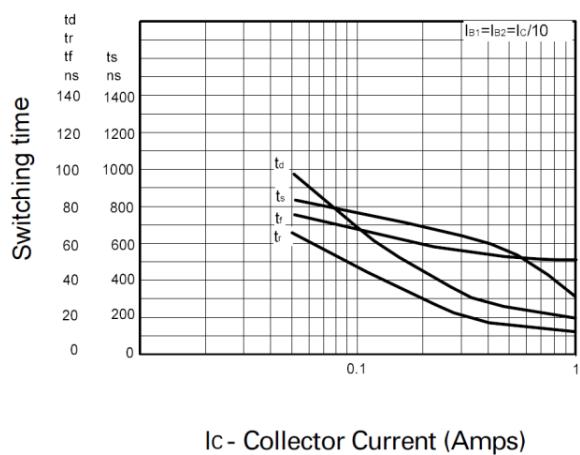
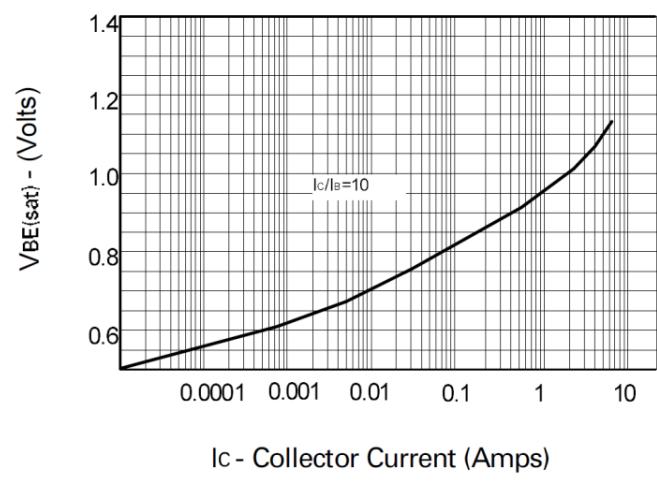
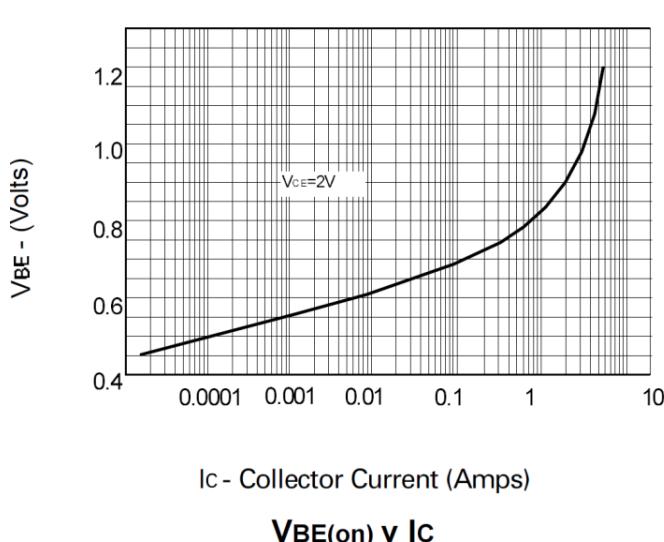
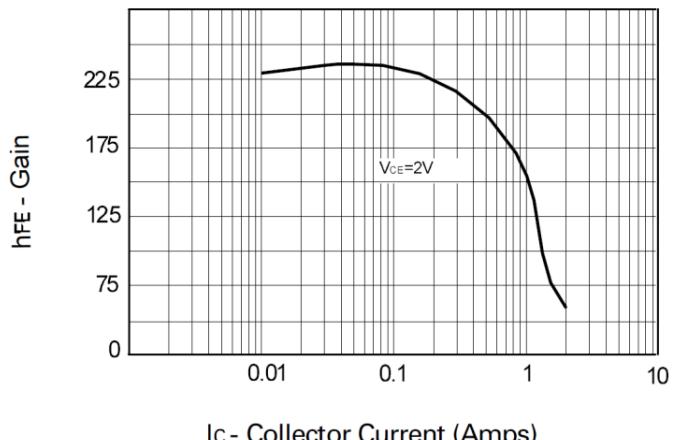
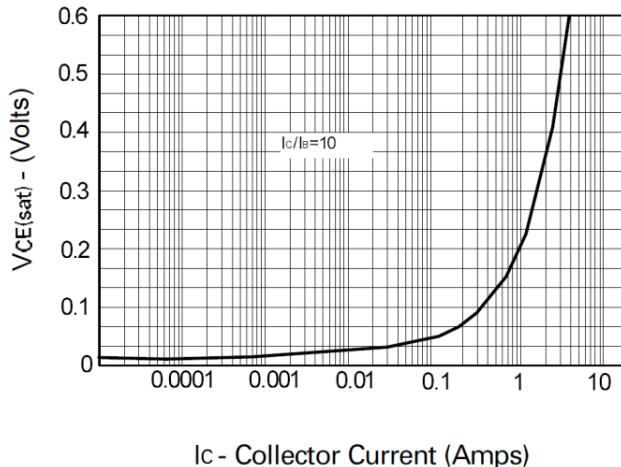
FZT753

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-120	—	—	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 12)	BV_{CEO}	-100	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	—	—	V	$I_E = -100\mu\text{A}$
Collector Cut-Off Current	I_{CBO}	—	<1	-100	nA	$V_{\text{CB}} = -100\text{V}$
		—	—	-10	μA	$V_{\text{CB}} = -100\text{V}, T_A = +125^\circ\text{C}$
Emitter Cut-Off Current	I_{EBO}	—	<1	-100	nA	$V_{\text{EB}} = -5.6\text{V}$
Collector-Emitter Saturation Voltage (Note 12)	$V_{\text{CE}(\text{sat})}$	—	-0.17	-0.3	V	$I_C = -1\text{A}, I_B = -100\text{mA}$
		—	-0.30	-0.5		$I_C = -2\text{A}, I_B = -200\text{mA}$
Base-Emitter Saturation Voltage (Note 12)	$V_{\text{BE}(\text{sat})}$	—	-0.9	-1.25	V	$I_C = -1\text{A}, I_B = -100\text{mA}$
Base-Emitter Turn-On Voltage (Note 12)	$V_{\text{BE}(\text{on})}$	—	-0.8	-1.0	V	$I_C = -1\text{A}, V_{\text{CE}} = -2\text{V}$
DC Current Gain (Note 12)	h_{FE}	70	200	—	—	$I_C = -50\text{mA}, V_{\text{CE}} = -2\text{V}$
		100	200	300		$I_C = -500\text{mA}, V_{\text{CE}} = -2\text{V}$
		55	170	—		$I_C = -1\text{A}, V_{\text{CE}} = -2\text{V}$
		25	55	—		$I_C = -2\text{A}, V_{\text{CE}} = -2\text{V}$
Current Gain-Bandwidth Product	f_T	100	140	—	MHz	$V_{\text{CE}} = -5\text{V}, I_C = -100\text{mA}$ $f = 100\text{MHz}$
Turn-On Time	t_{on}	—	40	—	ns	$V_{\text{CC}} = -10\text{V}, I_C = -500\text{mA}$
Turn-Off Time	t_{off}	—	600	—	ns	$I_{B1} = -I_{B2} = -50\text{mA}$
Output Capacitance	C_{obo}	—	—	30	pF	$V_{\text{CB}} = -10\text{V}, f = 1\text{MHz}$

Note: 12. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

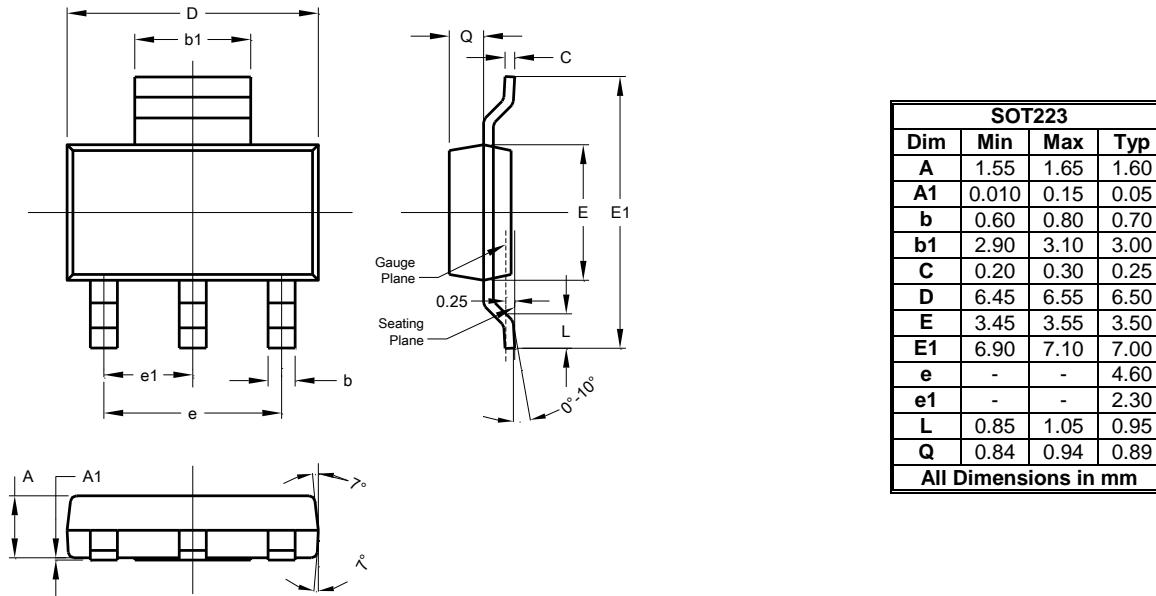
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Switching Speeds

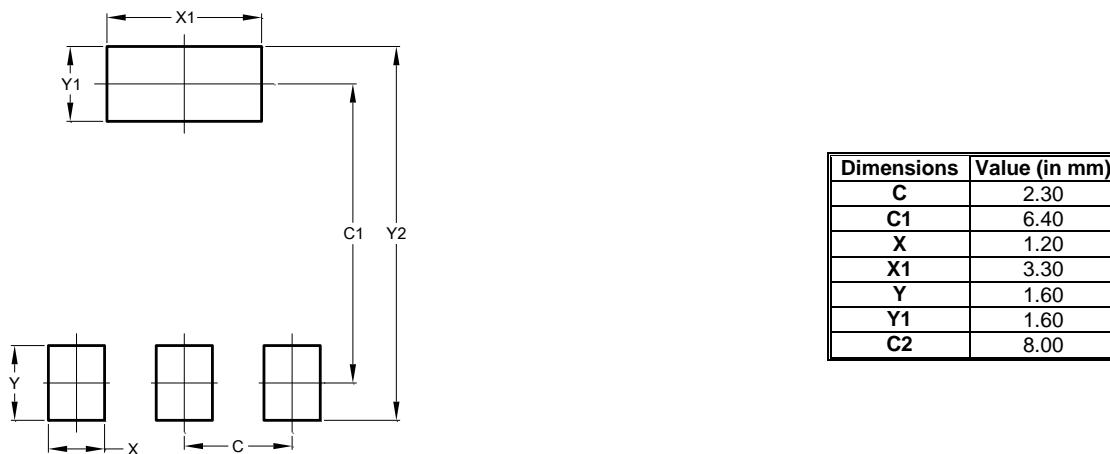
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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